捷多邦,专业PCBF**SN5**4LV@540A等SN74LVC540A OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Power Off Disables Outputs, Permitting Live Insertion
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and DIPs (J)

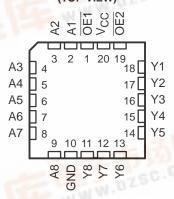
description

The SN54LVC540A octal buffer/driver is designed for 2.7-V to 3.6-V V_{CC} operation and the SN74LVC540A octal buffer/driver is designed for 1.65-V to 3.6-V V_{CC} operation.

These devices are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package that facilitate printed circuit board layout. SN54LVC540A . . . J OR W PACKAGE SN74LVC540A . . . DB, DW, OR PW PACKAGE (TOP VIEW)



SN54LVC540A ... FK PACKAGE (TOP VIEW)



The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LVC540A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LVC540A is characterized for operation from –40°C to 85°C.

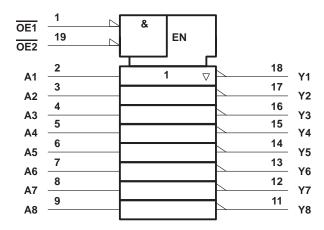
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FUNCTION TABLE

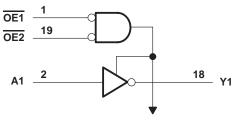
	INPUTS	OUTPUT	
OE1	OE2	Α	Y
L	L	L	Н
L	L	Н	L
Н	X	Χ	Z
Х	Н	Χ	Z

logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Channels



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Voltage range applied to any output in the high-impedance or power-off state, V _O (see Note 1)	_0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	-0.5 V to V_{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	
Continuous output current, IO	±50 mA
Continuous current through V _{CC} or GND	
Package thermal impedance, θ_{JA} (see Note 3): DB package	
DW package	
PW package	
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The value of $V_{\hbox{\scriptsize CC}}$ is provided in the recommended operating conditions table.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			SN54LVC540A		SN74L	VC540A	UNIT	
			MIN	MAX	MIN	MAX	UNII	
V	Supply voltage	Operating	2	3.6	1.65	3.6	V	
Vcc	Supply voltage	Data retention only	1.5		1.5		V	
		V _{CC} = 1.65 V to 1.95 V			0.65 × V _{CC}			
VIH	High-level input voltage	V _{CC} = 2.3 V to 2.7 V			1.7		V	
		V _{CC} = 2.7 V to 3.6 V	2		2			
		V _{CC} = 1.65 V to 1.95 V				0.35 × V _{CC}		
V_{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V				0.7	V	
		V _{CC} = 2.7 V to 3.6 V		0.8		0.8		
٧ _I	Input voltage		0	5.5	0	5.5	V	
\/ -	Output voltage	High or low state	0	Vcc	0	Vcc	V	
Vo	Output voltage	3 state	0	5.5	0	5.5	V	
		V _{CC} = 1.65 V				-4		
la	High lovel output ourrent	V _{CC} = 2.3 V				-8	mA	
ЮН	High-level output current	V _{CC} = 2.7 V		-12		-12		
		VCC = 3 V		-24		-24		
		V _{CC} = 1.65 V				4		
١,	Low-level output current	V _{CC} = 2.3 V				8	mA	
lOL		V _{CC} = 2.7 V		12		12		
		V _{CC} = 3 V		24		24		
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SN54LVC540A, SN74LVC540A OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN54	4LVC540/	Δ.	SN74	LVC540	A	UNIT
PARAMETER	TEST CONDITIONS	vcc	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNII
	Jan - 100 uA	1.65 V to 3.6 V				V _{CC} -0.2			
	ΙΟΗ = -100 μΑ	2.7 V to 3.6 V	V _{CC} -0.2						
	I _{OH} = -4 mA	1.65 V				1.2			
V_{OH}	I _{OH} = -8 mA	2.3 V				1.7			V
	I _{OH} = -12 mA	2.7 V	2.2			2.2			
	IOH = -12 IIIA	3 V	2.4			2.4			ı
	I _{OH} = -24 mA	3 V	2.2			2.2			
	lo. – 100 uA	1.65 V to 3.6 V						0.2	V
Va	I _{OL} = 100 μA	2.7 V to 3.6 V			0.2				
	I _{OL} = 4 mA	1.65 V						0.45	
VOL	I _{OL} = 8 mA	2.3 V						0.7	
	I _{OL} = 12 mA	2.7 V			0.4			0.4	
	I _{OL} = 24 mA	3 V			0.55			0.55	
lį	$V_{I} = 0 \text{ to } 5.5 \text{ V}$	3.6 V			±5			±5	μΑ
l _{off}	V _I or V _O = 5.5 V	0						±10	μΑ
I _{OZ}	V _O = 0 to 5.5 V	3.6 V			±15			±10	μΑ
	V _I = V _{CC} or GND	2014			10			10	
ICC	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}^{\ddagger}$ $10 = 0$	3.6 V			10			10	μΑ
ΔICC	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V			500			500	μΑ
C _i	V _I = V _{CC} or GND	3.3 V		4			4		pF
Со	$V_O = V_{CC}$ or GND	3.3 V		5.5			5.5		pF

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
t _{pd}	А	Υ		7.1	1	5.3	ns
t _{en}	OE	Υ		8	1	6.6	ns
^t dis	ŌĒ	Y		8.2	1	7.4	ns

[‡] This applies in the disabled state only.

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switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

			SN74LVC540A								
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} =		V _{CC} =	2.5 V 2 V	VCC =	2.7 V	V _{CC} =	3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	А	Υ	†	†	†	†		7.1	1.4	5.3	ns
t _{en}	ŌĒ	Υ	†	†	†	†		8	1.1	6.6	ns
^t dis	ŌĒ	Y	†	†	†	†		8.2	1.8	7.4	ns
t _{sk(o)} ‡				·				·		1	ns

[†] This information was not available at the time of publication.

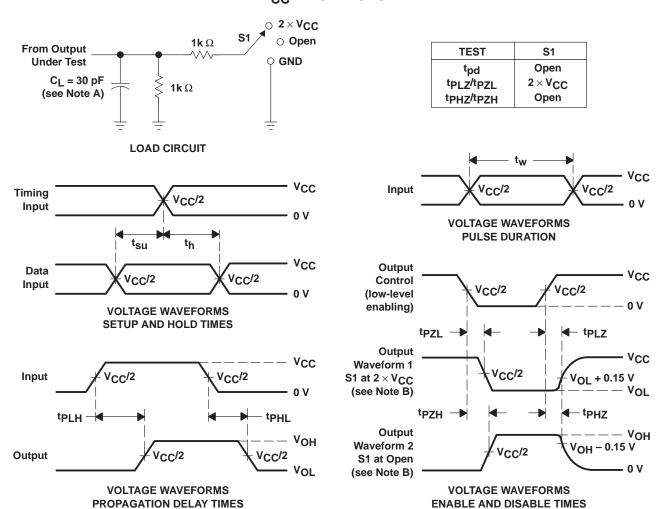
operating characteristics, $T_A = 25^{\circ}C$

PARAMETER			TEST CONDITIONS	V _{CC} = 1.8 V ± 0.15 V	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.3 V	UNIT
		CONDITIONS	TYP	TYP	TYP		
Const	Power dissipation capacitance	Outputs enabled	f = 10 MHz	†	†	31	nE
C _{pd} per buffer/driver	per buffer/driver	Outputs disabled	1 = 10 MH2	†	†	3	pF

[†] This information was not available at the time of publication.

[‡] Skew between any two outputs of the same package switching in the same direction

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$

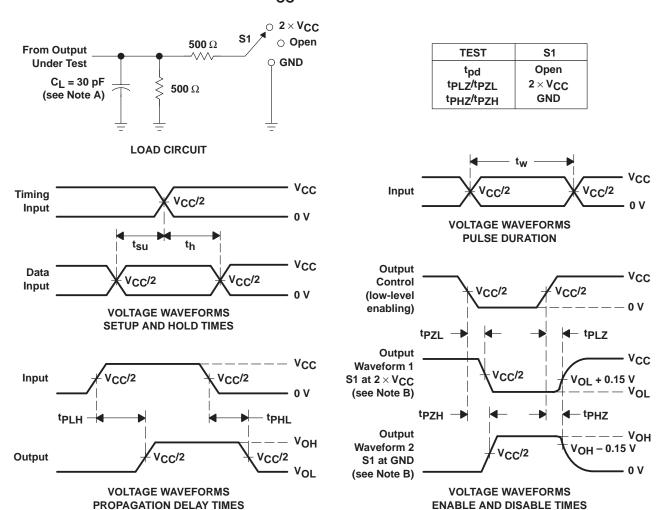


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq$ 2 ns. $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

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PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



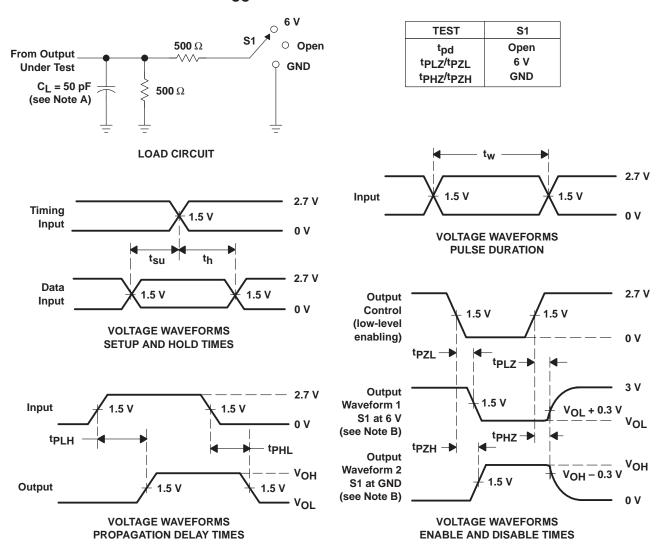
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms



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